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THz Source based on Laser Mixing

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Abstract

The concept of a THz source based on laser mixing is presented. A radiated power of $100 \mu\text{W}$ can be generated at 1-3 THz from laser powers of 25 mW if a photo detector with a bandwidth efficiency product of 360 GHz can be fabricated.

1. Introduction

Far-infrared (sub-millimetre wave) heterodyne radiometry is of significant importance for astrophysics and atmospheric research [1], [2]. Technology for the frequency range of 300 GHz to approximately 700 GHz is now sufficiently mature to be considered for application in space borne instruments [1]. There is, however, a strong push to go to the 1-3 THz range [1]-[3].

Apart from the availability of mixers operating at THz frequencies, there is the even more difficult problem of developing the required local oscillator sources [1]-[3]. The output power of solid-state Gunn-diode oscillators and multipliers drop off very rapidly above 700 GHz [1]-[3]. Today, the only feasible way to achieve THz radiation is by use of a far-infrared (FIR) gas laser that is pumped by a CO_2 gas laser [1]-[3]. This type of source is, however, quite bulky and heavy and certainly not suitable for space borne systems. Therefore, new techniques and technologies for THz sources are currently investigated by both ESA and NASA.

Compact, yet efficient, THz sources can possibly be obtained by the use of coherent optical techniques [4], [5]. The THz signal is generated by mixing of two laser signals in a suitable mixing element. Compact lasers such as semiconductor lasers or Nd:YAG lasers can be used together with fibre-optic technology resulting in THz sources that may be usable in space borne systems. Such a source has been investigated as part of the ESA program, and the basic concepts are presented in this paper together with a performance estimation.

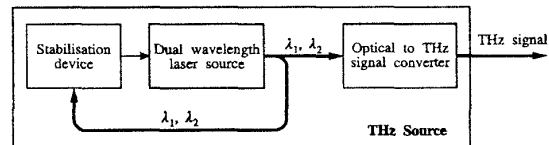


Figure 1: The principal parts of a THz source based on laser mixing.

2. THz source principle

As shown in Fig. 1, any type of THz source based on laser mixing consists of three distinctive parts:

1. A dual wavelength laser source.
2. A Stabilisation device.
3. An Optical to THz signal converter.

The dual wavelength laser source generates two optical signals with a frequency offset corresponding to the frequency of the desired THz signal. A stabilisation device is necessary to ensure the correct frequency offset, to stabilise the frequency and to remove laser phase noise. The THz signal is generated from the two offset stabilised optical signals by mixing in a suitable optical to THz signal converter.

3. Stabilised dual wavelength laser source

The following laser sources have been identified as possible candidates [4], [5]:

1. Two separate lasers:
 - a. Semiconductor lasers.
 - b. Solid state lasers.
2. A dual wavelength laser:
 - a. Solid state parametric oscillator.

All of these require stabilisation by optical offset phase locking for the reasons described above.

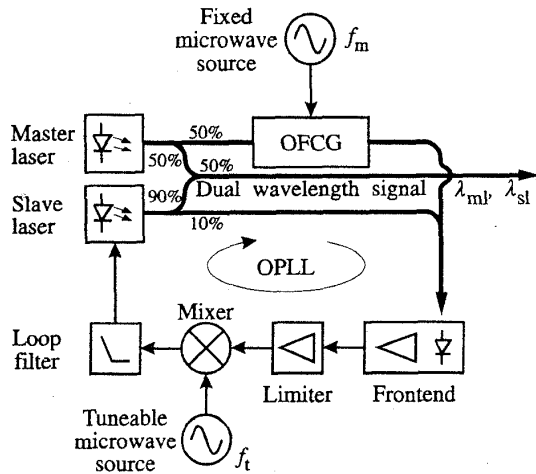


Figure 2: Schematic of the OPLL stabilised dual wavelength laser source.

Semiconductor lasers would be highly desirable for space applications. Commercially available devices, however, require wideband phase locking [6]. In contrast, solid state lasers only require narrowband phase locking [7]. The parametric oscillator has been used with promising results [8]. However, it is far too less developed for space application. At present, the most promising solution seems to be two separate compact Nd:YAG lasers. These are commercially available, are developed to an extent that enable application in space, and only require narrowband phase locking.

The dual wavelength laser source based on two lasers stabilised by an optical phase locked loop (OPLL) is shown in Fig. 2. It consists of a free-running master laser, a locked slave laser, an optical frequency comb generator (OFCG), a fixed microwave source, an optical frontend, a limiting microwave amplifier chain, a microwave mixer, a tuneable microwave source and a loop filter.

As no THz reference exists, it is necessary to use harmonic phase locking. The harmonics are generated optically by the OFCG shown in Fig. 3. It consists of a microwave resonant phase modulator placed inside a Fabry-Perot cavity [8]-[10]. As shown, it generates a large set of optical sidebands as harmonics of f_m centred around the frequency of the master laser, f_{ml} . The OFCG can be implemented as a monolithic device, and comb widths of more than 3 THz have been obtained [9]. Harmonic optical phase locking with this type of OFCG has been demonstrated at frequencies as high as 1 THz [10].

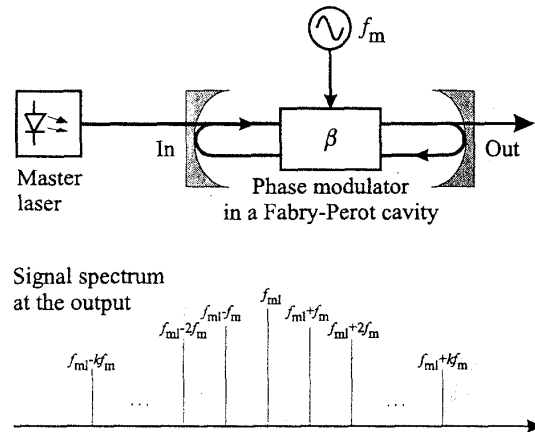


Figure 3: Principle of the optical frequency comb generator.

The optical frequency comb is injected into the photodiode of the frontend together with the signal from the slave laser. The beat signal, between the k^{th} sideband and the slave laser signal, is amplified and limited in order to obtain a constant power level at the input of the mixer no matter which sideband the slave laser is beating against. In the mixer, the beat signal is compared to the signal from a tuneable microwave source. The resulting phase error difference signal is feed to the slave laser through the loop filter. This forces the slave laser to track the master laser at an offset of $f_{\text{THz}} = k \cdot f_m + f_t$. The offset phase locking ensures a frequency stability, resolution and accuracy that all are equal to k times that of the fixed microwave source at f_m . The frequency of the THz offset can be coarse tuned by stepping the slave laser through the OFCG sidebands and fine tuned by means of the tuneable microwave source. Exact determination and control of the THz offset can be obtained by use of the available OPLL signals and additional and simple control electronics [4], [5].

4. Optical to THz signal converter

As the final step, the THz offset dual wavelength optical signal must be converted into a real THz signal. The following conversion methods have been identified as possible candidates [4], [5]:

1. Heterodyne conversion in a photo detector:
 - a. Travelling wave PIN photo detector.
 - b. Schottky MSM photo detector.
 - c. Photoconductive MSM photo detector.

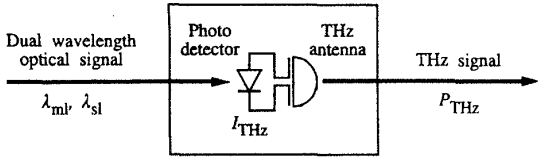


Figure 4: Principle of the optical to THz signal converter based on heterodyne conversion.

2. Optical parametric conversion in a non-linear crystal.
3. Optical/THz super heterodyne detection in a Schottky diode.

At present, heterodyne conversion seems to be the most efficient of the three [4], [5]. However, optical parametric conversion may show potential if better non-linear materials are found [4], [5].

The basic principle of the heterodyne conversion concept is illustrated in Fig. 4. The two THz offset phase locked optical signals are coupled into the photo detector by use of a microlensed fibre. This fibre is optimized for the specific detector in use and ensures optimum coupling of light into the device. A THz photo current, I_{THz} , is generated in the photo detector by the heterodyning process. In general, the current depends on the power of the two optical signals and on the external bandwidth-efficiency product of the photo detector. The electrodes of the photo detector are coupled directly with a THz antenna which is driven by the current. This results in a radiated THz signal with a power of P_{THz} . The power level depends on the photo generated current, the photo detector and antenna parasitics, the antenna impedance and the antenna radiation efficiency.

State of the art results for the bandwidth efficiency product of the three different detector types are shown in Fig. 5 together with analytical calculations as well as detailed simulations. As seen, approximately the same performance can be achieved with all three types. Products of 76, 118 and 102 GHz have been achieved with travelling wave (TW) PIN [11], Schottky metal semiconductor metal (S-MSM) [12] and photoconductive (PC) MSM [12] detectors, respectively. It is estimated that the use of quantum structures, such as quantum wires (QW), can significantly improve the results of the PIN [13]. Also the results of the MSM have potential for improvement [14]. Lowering of the device temperature also holds potentials for improvement [4], [5].

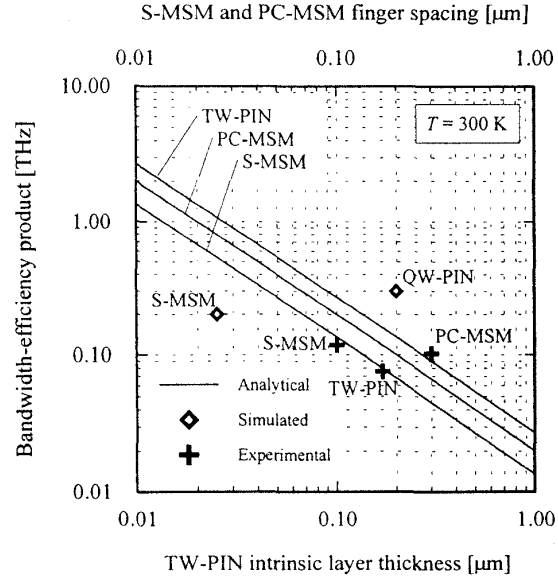


Figure 5: Bandwidth efficiency product of PIN photo detectors versus their intrinsic layer thickness, and of Schottky MSM and Photoconductive MSM photo detectors versus their finger spacing.

5. Performance estimation

The performance estimation that is summarised here is based on the results from two ESA research projects. Further details are found in [4], [5].

It is assumed that two compact Nd:YAG lasers with output powers of 25 mW are used. Further it is assumed that the fibre coupling ratios are as specified in Fig. 2.

A monolithic OFCG is assumed for the sideband generation. It is driven at a frequency, f_m , of 19.98 GHz, and a modulation index, β , of approximately $\pi/2$ is required to cover the 1-3 THz frequency band using the 50th to 150th sideband. This will give a sideband slope efficiency of 5 dB/THz which can easily be compensated by the limiter in the OPLL.

A tuning range of 1-20 GHz for f_i will be required to enable continuous tuning between each of the OFCG sidebands.

For the simulated output power in the 150th sideband a carrier to noise density ratio at the input of the OPLL of 100 dBHz has been found based on the data of commercially available lasers, frontend and loop electronics. This gives a loop SNR of more than 30 dB for loop bandwidths as wide as 1 MHz. Such a bandwidth is more than adequate for Nd:YAG lasers [7].

Table 1: Estimated parameter values.

Parameter	Value
Radiated THz power	100 μ W at 1-3 THz
Laser output powers	25 mW (each)
Bandwidth efficiency	360 GHz
OFCG mod. index	$\pi/2$ at 20 GHz
OPLL bandwidth	$\ll 1$ MHz
Phase noise	~ -90 dBc/Hz at 1 MHz
Frequency accuracy	~ 10 -30 kHz at 1-3 THz

The resulting phase noise and frequency precision of the THz signal will for 1 and 3 THz, respectively, be given by 50 and 150 times the phase noise and frequency precision of the signal at frequency f_m .

Besides the OFCG, the implementation of the OPLL is straight forward and can be based on commercially available components. Some development effort is expected for the implementation of an OFCG with the above requirements.

Due to the fibre coupling ratios, the optical power delivered to the converter is 6.25 mW from the master laser and 11.25 mW from the slave laser. For the converter with a device integrated antenna, a current to radiated power efficiency of 50 W/A² is assumed. To obtain a radiated THz signal power level of 100 μ W, the photo detector needs a bandwidth efficiency product of 360 GHz for the 3 THz signal. Comparing this to the state of the art results, it is seen that significant development challenges lie ahead for the converter as the photo detector bandwidth efficiency products are a factor of 3-5 too low. However, in this respect, the simulation results of Fig. 5 are encouraging. The main parameter values are summarised in table 1.

6. Conclusion

A promising concept for a compact 1-3 THz source has been presented together with an estimation of the achievable performance and the component requirements. Major parts of the source can be implemented with commercially available components. However, implementation of the required photo detector with a 360 GHz bandwidth efficiency product represents a significant challenge. The source can be expected to deliver 100 μ W of radiated THz power with a low phase noise and a high frequency precision. Most importantly, it has potential for use in space borne radiometry instruments.

Acknowledgements

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References

- [1] M.A. Frerking, "Submillimeter source needs for NASA missions," Proceedings of SPIE, vol. 2145, 1994, pp. 222-229.
- [2] T.G. Phillips, "THz source requirements for astrophysics receivers," Proceedings of SPIE, vol. 2145, 1994, pp. 230-238.
- [3] B.D. Guenther, "Terahertz sources," Proceedings of SPIE, vol. 2145, 1994, pp. 120-129.
- [4] U. Gliese et. al., "Feasibility study of optical 1-3 THz signal source," Tech. Report R589, ESTEC contract No. 140409, Tech. Univ. of Denmark, Dept. of Electromagnetic Systems, 1994.
- [5] U. Gliese, "THz signal generation by laser mixing," Tech. Report R630, ESTEC Contract No. 11653/95/NL/PB, Tech. Univ. of Denmark, Dept. of Electromagnetic Systems, 1996.
- [6] U. Gliese et. al., "A wideband heterodyne optical phase locked loop for generation of 3-18 GHz microwave carriers," Photonics Tech. Lett., vol. 4, no. 8, 1992, pp. 936-938.
- [7] U. Gliese et. al., "Generation of microwave signals with lasers - Optical offset phase locking of Nd:YAG lasers," Tech. Report AR316, Tech. Univ. of Denmark, Dept. of Electromagnetic Systems, 1993.
- [8] L.R. Brothers et. al., "Terahertz optical frequency comb generation and phase locking of an optical parametric oscillator at 665 GHz," Optics Lett., vol. 19, no. 4, 1994, pp. 245-247.
- [9] M. Kourogi et. al., "A monolithic optical frequency comb generator," Photonics Tech. Lett., vol. 6, no. 2, 1994, pp. 214-217.
- [10] K. Nakagawa et. al., "Highly precise 1-THz optical frequency difference measurement of 1.5 μ m molecular absorption lines," Optics Lett., vol. 20, no. 4, 1995, pp. 410-412.
- [11] K.S. Giboney et. al., "Travelling-wave photodetectors with 172-GHz bandwidth and 76-GHz bandwidth efficiency product," Photonics Tech. Lett., vol. 7, no. 4, 1995, pp. 412-414.
- [12] S.Y. Chou et. al., "Ultrafast nanoscale metal-semiconductor-metal photodetectors on bulk and low-temperature grown GaAs," Applied Phys. Lett., vol. 61, no. 7, 1992, pp. 819-821.
- [13] D.L. Crawford et. al., "Comparison of bulk and quantum wire photodetectors," App. Phys. Lett., vol. 58, no. 15, 1991, pp. 1629-1631.
- [14] S.Y. Chou et. al., "Tera-Hertz GaAs metal-semiconductor-metal photodetectors with nanoscale finger spacing and width," Int. Elec. Devices. Meeting Digest, 1991, pp. 745-748.